

# VFGC Crystal Oscillators HCMOS 3.3V or 5V 5X3.2mm Surface Mount 500 KHz to 135 MHz

# Features

- Wide frequency range with 3.3V or 5V supply options
- High speed-Low jitter CMOS output with tristate
- Small SMD package-5X3.2mm
- Extra low profile for slimline applications
- Stability options: 100, 50 or 25ppm
- Commercial or industrial temperature range
- Rugged, hermetic package for automated assembly

# **Typical Applications**

Telecom/networking systems that require low jitter clocks

- ✓ DSL
- ✓ Gigabit Ethernet,
- ✓ Fibre channel
- ✓ Optical networking

Mobile systems requiring small size

- v v PDA
- ✓ Wireless Lan
- ✓ Notebook computer
- ✓ PCMCIA
- ✓ Memory modules

# Description

Valpey Fisher's GC surface mount crystal oscillator provides waveforms for clocking HCMOS and TTL circuits. The new 5X3.2mm footprint package provides the performance of larger oscillators with a level of board space reduction achieved. ASIC technology is used to accomplish size reduction and enhance performance and reliability. Low jitter output signals are generated via the use of hi-Q fundamental or overtone miniature quartz resonators. Along with the extra low profile height, they are ideal for space critical portable or hand-held equipment, while their tight tolerance and low noise performance makes them also the ideal choice for high data rate telecom applications. The wide range of frequencies offered, many stability options, 5.0V or 3.3 volt supply, and industrial temperature ranges, makes this model attractive for any application requiring extreme size reduction. Tape and reel packaging is standard.

CONNECTION	<b>CONNECTION</b>	
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PAD 1	Tristate
PAD 2	Ground and Case
PAD 3	Output
PAD 4	+3.3V or +5V V <sub>DD</sub>







VFGC **Crystal Oscillators HCMOS 3.3V or 5V 5X3.2mm Surface Mount** 500 KHz to 135 MHz

### **ELECTRICAL SPECIFICATIONS**

Frequency Range	3.3V Supply 5.0V Supply	500KF 500KF	Hz to 135MHz Hz to 100MHz		
Frequency Stability					
Includes calibration at 2	100, 5	50 or 25ppm			
temperature, change of input voltage.					
change of load, shock an	d vibration				
Input Voltage, V <sub>DD</sub>		3.3 +/-10%	or 5.0 +/-10%		
Output Levels	(CMOS)	1 level:	: V <sub>DD</sub> -0.4 min		
•		'0' leve	1: 0.40 max		
<b>Output Load</b> 15pF typ. 30pF max					
Jitter	8 ps RMS max				
Symmetry	45/55 per	rcent @ 50	)% V <sub>DD</sub>		
Aging (typical)		0			
First year		3ppm			
After first year		1ppm/yr			
Input Current (Max)	3.3V	5.0V	Units		
0.5-9.999 MHz	7	10	mA		
10-19.999 MHz	7	15	mA		
20-31.999 MHz	12	25	mA		
32-49.999 MHz	20	35	mA		
50-79.999 MHz	25	50	mA		
80-99.999 MHz	30	60	mA		
100-135.0 MHz	40	80	mA		
Rise and Fall Times (Max)					
0.5-31.99 MHz	10	10	ns		
32-49.99 MHz	10	6	ns		
50-79.99 MHz	8	5	ns		
80-99.99 MHz	5	5	ns		
100-135.0 MHz	4	4	ns		
Input Requirements fo	r Pad 1·				

"1": On-Pad 1 may float or 2.8V min "0": Tristate-Pad 1 requires 0.4V max

## **ENVIRONMENTAL SPECIFICATIONS**

Temperature					
Operating	Commercial:	0° to 70°C			
	Industrial:	-40°C to +85°C			
Storage		-55° to +125°C			
Shock- 1000 Gs, 0.35 ms, <sup>1</sup> / <sub>2</sub> sine wave, 3 shocks in each plane					
Vibration- 10-2	2000 Hz of .06" d.	a. or 10 Gs, whichever is less			
Humidity- Resi	istant to 85° R.H. a	at 85°C			

### **MECHANICAL SPECIFICATIONS**

Leak- MIL STD 883, Method 1014, Condition A1 Case- Ceramic with hermetic resistance-welded metal lid Pads- Solderable gold over nickel Marking- Epoxy ink or laser engraved Resistance to solvents- MIL STD 202, Method 215

#### MARKING SPECIFICATION

The format for the marking is:



